

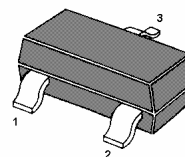
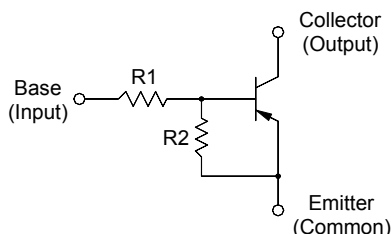
# MMBTRA116SS...MMBTRA122SS

## PNP Silicon Epitaxial Planar Transistor

for switching, interface circuit and drive circuit applications

### Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process



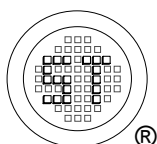
1. Base 2. Emitter 3. Collector  
SOT-23 Plastic Package

### Resistor Values

Type	R1 (KΩ)	R2 (KΩ)
MMBTRA116SS	1	10
MMBTRA117SS	2.2	2.2
MMBTRA118SS	2.2	10
MMBTRA119SS	4.7	10
MMBTRA120SS	10	4.7
MMBTRA121SS	47	10
MMBTRA122SS	100	100

### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Output Voltage	$-V_o$	50	V
Input Voltage	$V_i$	MMBTRA116SS	- 10, 5
		MMBTRA117SS	- 12, 10
		MMBTRA118SS	- 12, 5
		MMBTRA119SS	- 20, 7
		MMBTRA120SS	- 30, 10
		MMBTRA121SS	- 40, 15
		MMBTRA122SS	- 40, 10
Output Current	$-I_o$	100	mA
Total Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_s$	- 55 to + 150	$^\circ\text{C}$



**SEMTECH ELECTRONICS LTD.**

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ISO/TS 16949 : 2002  
Certificate No. 05103



ISO 14001:2004  
Certificate No. 7116



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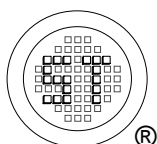
Dated : 29/10/2007

# MMBTRA116SS...MMBTRA122SS

## Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain					
at $-V_o = 5\text{ V}$ , $-I_o = 5\text{ mA}$	MMBTRA116SS	33	-	-	-
at $-V_o = 5\text{ V}$ , $-I_o = 20\text{ mA}$	MMBTRA117SS	20	-	-	-
at $-V_o = 5\text{ V}$ , $-I_o = 10\text{ mA}$	MMBTRA118SS	33	-	-	-
at $-V_o = 5\text{ V}$ , $-I_o = 10\text{ mA}$	MMBTRA119SS	30	-	-	-
at $-V_o = 5\text{ V}$ , $-I_o = 10\text{ mA}$	MMBTRA120SS	24	-	-	-
at $-V_o = 5\text{ V}$ , $-I_o = 5\text{ mA}$	MMBTRA121SS	33	-	-	-
at $-V_o = 5\text{ V}$ , $-I_o = 5\text{ mA}$	MMBTRA122SS	62	-	-	-
Output Cutoff Current at $-V_o = 50\text{ V}$	$-I_{O(OFF)}$	-	-	500	nA
Input Current at $-V_i = 5\text{ V}$					
MMBTRA116SS		-	-	7.2	mA
MMBTRA117SS		-	-	3.8	
MMBTRA118SS		-	-	3.8	
MMBTRA119SS		-	-	1.8	
MMBTRA120SS		-	-	0.88	
MMBTRA121SS		-	-	0.16	
MMBTRA122SS		-	-	0.15	
Output Voltage					
at $-I_o = 10\text{ mA}$ , $-I_i = 0.5\text{ mA}$	MMBTRA116SS	-	-	0.3	V
at $-I_o = 10\text{ mA}$ , $-I_i = 0.5\text{ mA}$	MMBTRA117SS	-	-	0.3	
at $-I_o = 10\text{ mA}$ , $-I_i = 0.5\text{ mA}$	MMBTRA118SS	-	-	0.3	
at $-I_o = 10\text{ mA}$ , $-I_i = 0.5\text{ mA}$	MMBTRA119SS	-	-	0.3	
at $-I_o = 10\text{ mA}$ , $-I_i = 0.5\text{ mA}$	MMBTRA120SS	-	-	0.3	
at $-I_o = 10\text{ mA}$ , $-I_i = 0.5\text{ mA}$	MMBTRA121SS	-	-	0.3	
at $-I_o = 5\text{ mA}$ , $-I_i = 0.25\text{ mA}$	MMBTRA122SS	-	-	0.3	
Input Voltage (ON)					
at $-V_o = 0.3\text{ V}$ , $-I_o = 20\text{ mA}$	MMBTRA116SS	-	-	3	V
at $-V_o = 0.3\text{ V}$ , $-I_o = 20\text{ mA}$	MMBTRA117SS	-	-	3	
at $-V_o = 0.3\text{ V}$ , $-I_o = 20\text{ mA}$	MMBTRA118SS	-	-	3	
at $-V_o = 0.3\text{ V}$ , $-I_o = 20\text{ mA}$	MMBTRA119SS	-	-	2.5	
at $-V_o = 0.3\text{ V}$ , $-I_o = 2\text{ mA}$	MMBTRA120SS	-	-	3	
at $-V_o = 0.3\text{ V}$ , $-I_o = 2\text{ mA}$	MMBTRA121SS	-	-	5	
at $-V_o = 0.3\text{ V}$ , $-I_o = 1\text{ mA}$	MMBTRA122SS	-	-	3	
Input Voltage (OFF)					
at $-V_{CC} = 5\text{ V}$ , $-I_o = 100\text{ }\mu\text{A}$	MMBTRA116SS	0.3	-	-	V
MMBTRA117SS		0.5	-	-	
MMBTRA118SS		0.3	-	-	
MMBTRA119SS		0.3	-	-	
MMBTRA120SS		0.8	-	-	
MMBTRA121SS		1	-	-	
MMBTRA122SS		0.5	-	-	
Transition Frequency at $-V_o = 10\text{ V}$ , $-I_o = 5\text{ mA}$	$f_T$ <sup>1)</sup>	-	250	-	MHz

<sup>1)</sup> Characteristic of transistor only.



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